

FORM PTO-1449
INFORMATION DISCLOSURE STATEMENT

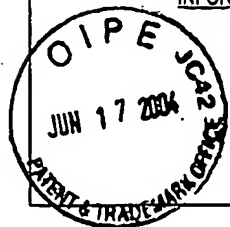
MMB DOCKET NO. 1890-0061

APPLICATION NO.: 10/780,276

APPLICANT(S): Tilke et al.

FILING DATE: February 17, 2004

GROUP ART UNIT: To be assigned



U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
TT	AA	5,121,185	June 9, 1992	Tamba et al.	—	—	
TT	AB	2002/0158308 A1	October 31, 2002	Huber et al.	—	—	
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
TT	AL	DE 100 44 838 A1	April 4, 2002	Germany	—	—	Yes No
	AM						Yes No
	AN						Yes No
	AO						Yes No
	AP						Yes No

OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

TT	AQ	1	O, Kenneth K., and Brad W. Scharf, "Effects of Buried Layer Geometry on Characteristics of Double Polysilicon Bipolar Transistors," IEEE Electron Device Letters, Vol., 19, No. 5, © May 1998, (3 pages).
	AR	1	
	AS	1	

EXAMINER

Thien Lam

DATE CONSIDERED

04/28/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicants.